

NPN Epitaxial Silicon Transistor

KSC2328A

Features

- Audio Power Amplifier Application
- Complement to KSA928A
- 3 W Output Application

ABSOLUTE MAXIMUM RATINGS

(Values are at $T_A = 25$ °C unless otherwise noted.)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	30	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	2	Α
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

(Values are at $T_A = 25$ °C unless otherwise noted.) (Note 2)

Symbol	Parameter	Value	Unit
P _D	Power Dissipation	1000	mW
	Derate Above 25°C	8.0	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	125	°C/W

^{2.} PCB size: FR-4, 76 mm \times 114 mm \times 1.57 mm (3.0 inch \times 4.5 inch \times 0.062 inch) with minimum land pattern size.

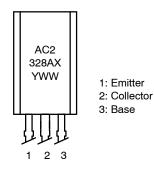




TO-92 3 LF CASE 135AM

TO-92 3 CASE 135AP

MARKING DIAGRAM



A = Assembly Code C2328A = Device Code X = O / Y YWW = Date Code

ORDERING INFORMATION

Device	Package	Shipping
KSC2328AYTA	TO-92 3 LF (Pb-Free)	2000 / Fan–Fold

DISCONTINUED (Note 1)

KSC2328AOTA	TO-92 3 LF (Pb-Free)	2000 / Fan–Fold
KSC2328AYBU	TO-92 3 (Pb-Free)	6000 / Bulk Bag

DISCONTINUED: These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.

KSC2328A

ELECTRICAL CHARACTERISTICS

(Values are at $T_A = 25$ °C unless otherwise noted.)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	30	-	-	V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{ mA}, I_B = 0$	30	-	-	V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 1 \text{ mA}, I_C = 0$	5	ı	-	V
I _{CBO}	Collector Cut-Off Current	V _{CB} = 30 V, I _E = 0	-	-	100	nA
I _{EBO}	Emitter Cut-Off Current	V _{EB} = 5 V, I _C = 0	-	-	100	nA
h _{FE}	DC Current Gain	V _{CE} = 2 V, I _C = 500 mA	100	-	320	
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} = 2 V, I _C = 500 mA	-	-	1.0	V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 1.5 A, I _B = 0.03 A	-	-	2.0	V
f _T	Current Gain Bandwidth Product	V _{CE} = 2 V, I _C = 500 mA	-	120	-	MHz
C _{ob}	Collector Output Capacitance	V _{CB} = 10 V, I _E = 0, f = 1 MHz	-	30	_	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

h_{FE} CLASSIFICATION

Classification	0	Y
h _{FE}	100 ~ 200	160 ~ 320

KSC2328A

TYPICAL PERFORMANCE CHARACTERISTICS

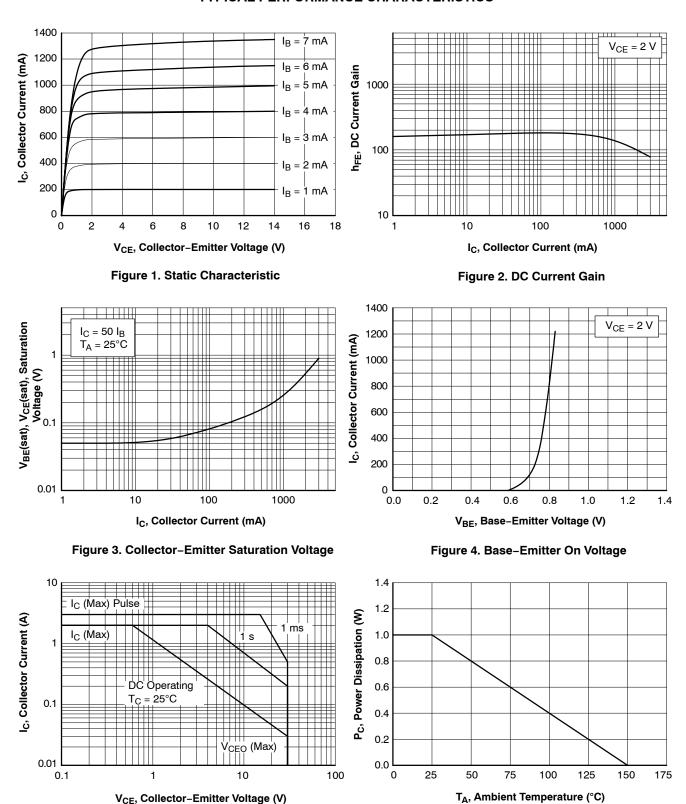
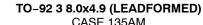


Figure 6. Power Derating

Figure 5. Safe Operating Area





CASE 135AM ISSUE B

DATE 14 JAN 2021



- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, GATE REMAINS AND TIE BAR PROTRUSIONS.
- 4. DIMENSION & AND &2 DOES NOT INCLUDE DAMBAR PROTRUSION.
 DIMENSION &2 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

	MILLIMETERS				
DIM	MIN.	N□M.	MAX.		
Α	3.70	3.90	4.10		
A1	1.25	1.45	1.65		
b	0.35	0.50	0.60		
b2	0.62		0.78		
C	0.35	0.45	0.55		
D	7.80	8.00	8,20		
Ε	4.70	4.90	5.10		
E2	3.70	3.90	4.10		
е	1.27 BSC				
e2	2.50 BSC				
F		2.45 REF			
L	13.00 REF				
L2	1.50		1.90		
L3	2,60		3,40		
L4	10.40 REF				

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END VIEW

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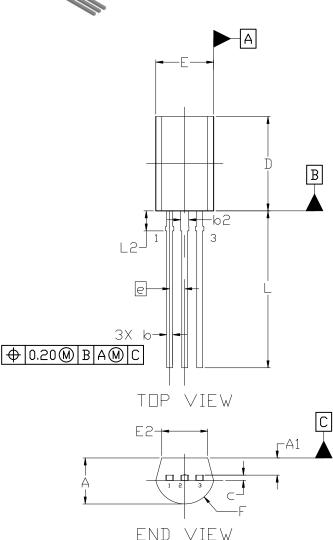
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- 4. DIMENSION 6 AND 62 DOES NOT INCLUDE DAMBAR PROTRUSION. DIMENSION 62 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

	MILLIMETERS			
DIM	MIN.	N□M.	MAX.	
Α	3.70	3.90	4.10	
A1	1.25	1.45	1.65	
b	0.40	0.50	0.60	
b2	0.62		0.78	
С	0.35	0.45	0.55	
D	7.80	8.00	8.20	
E	4.70	4.90	5.10	
E2	3.70	3.90	4.10	
е	1.27 BSC			
F	2.45 REF			
L	13.30		14.20	
L2	1.70 REF			

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